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"Reply under 37 CFR 1.116
 --Expedited Procedure--
 Examining Group 2811

ATTORNEY DOCKET NO.: LOTFI 22-2

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ashraf W. Lotfi, *et al.*

Serial No.: 09/448,856

Filed: November 23, 1999

Title: SiC NMOSFET FOR USE AS A POWER SWITCH AND
A METHOD OF MANUFACTURING THE SAME

Group: 2811

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Examiner: Ori Nadav

DEC 10 2002

TECHNOLOGY CENTER 2800

Commissioner for Patents
Washington, D.C. 20231

I hereby certify that this correspondence is being facsimile
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EDITH SHEIK
Typed or printed name of person signing this certificate

Edith Sheik
Signature

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.116

In response to the Examiner's Action mailed October 11, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

(1) Please amend Claim 44 as follows:

44. (Amended) A semiconductor device, comprising: